

Description

The SX280N12MP uses advanced technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 10V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

$V_{DS} = 120V$ (**Type: 135V**) $I_D = 280A$

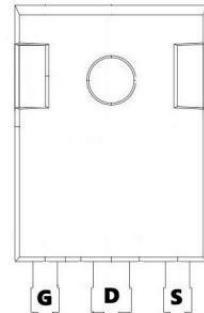
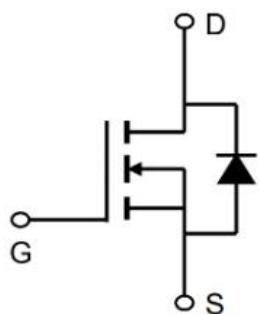
$R_{DS(ON)} < 3.6m\Omega$ @ $V_{GS}=10V$

Application

BMS

UPS

Power Management Switches

**Absolute Maximum Ratings ($T_c=25^\circ C$ unless otherwise noted)**

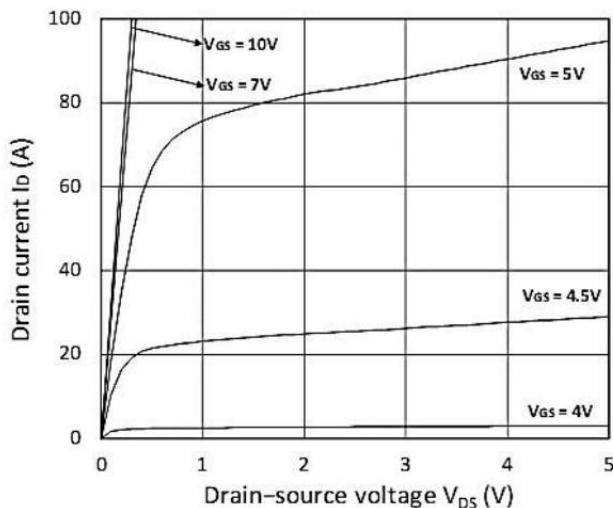
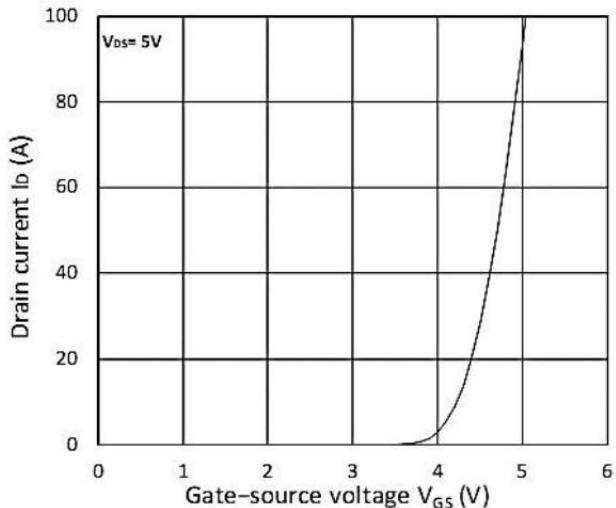
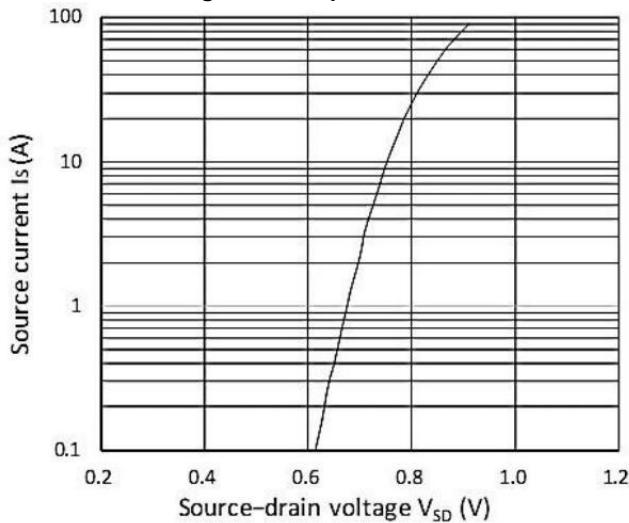
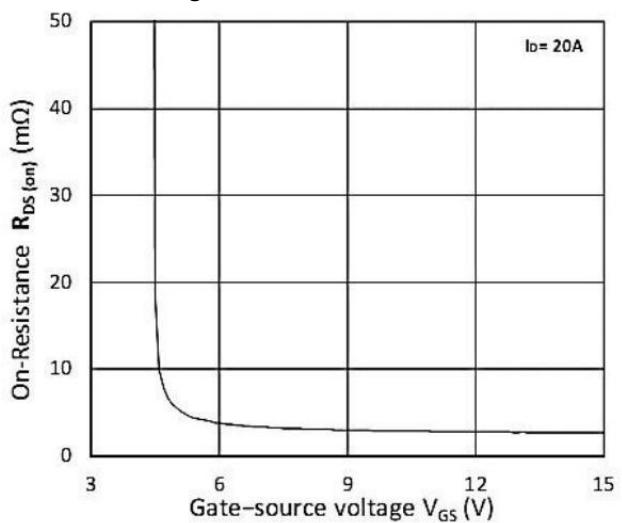
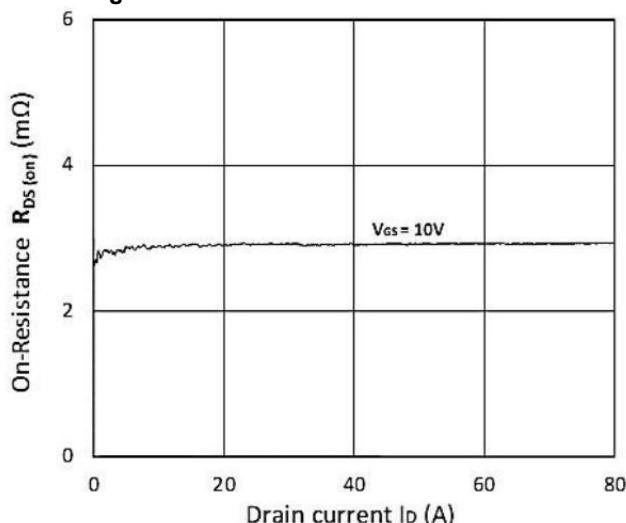
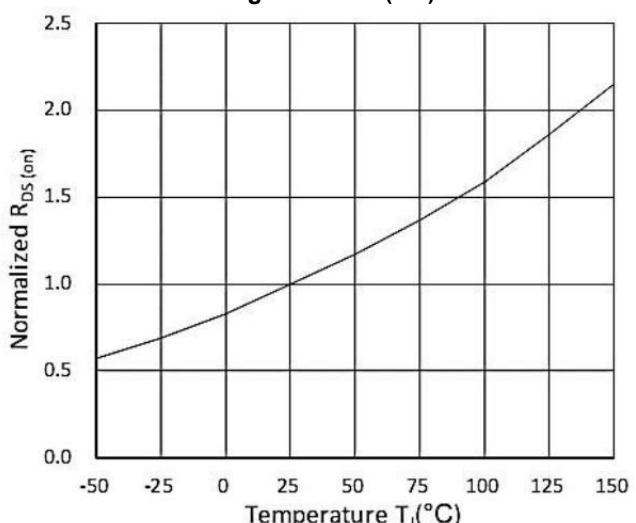
Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	120	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D@T_c=25^\circ C$	Continuous Drain Current, $V_{GS} @ 10V$	280	A
$I_D@T_c=100^\circ C$	Continuous Drain Current, $V_{GS} @ 10V$	163	A
IDM	Pulsed Drain Current	840	A
EAS	Single Pulse Avalanche Energy	520.2	mJ
I_{AS}	Avalanche Current	45	A
$P_D@T_c=25^\circ C$	Total Power Dissipation ⁴	240	W
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ C$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ C$
R_{eJA}	Thermal Resistance Junction-Ambient	62	$^\circ C/W$
R_{eJC}	Thermal Resistance Junction-Case	0.35	$^\circ C/W$

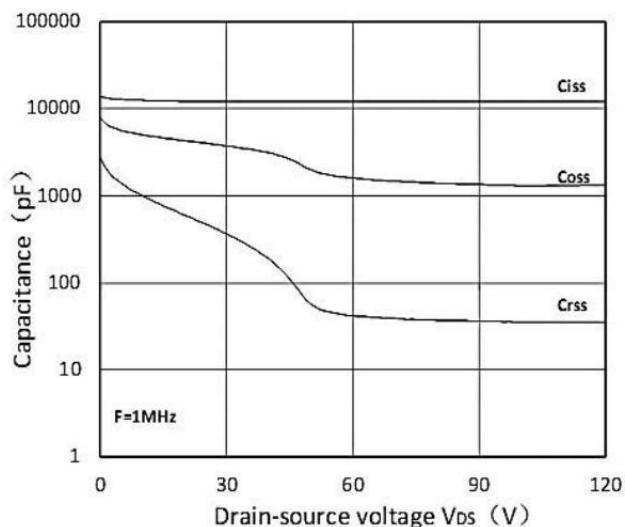
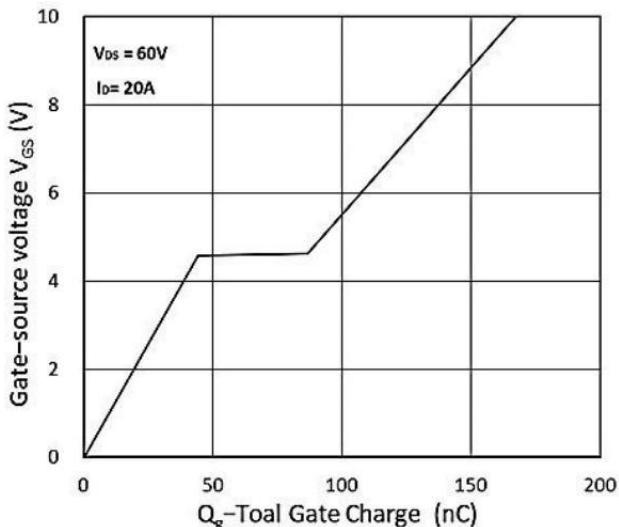
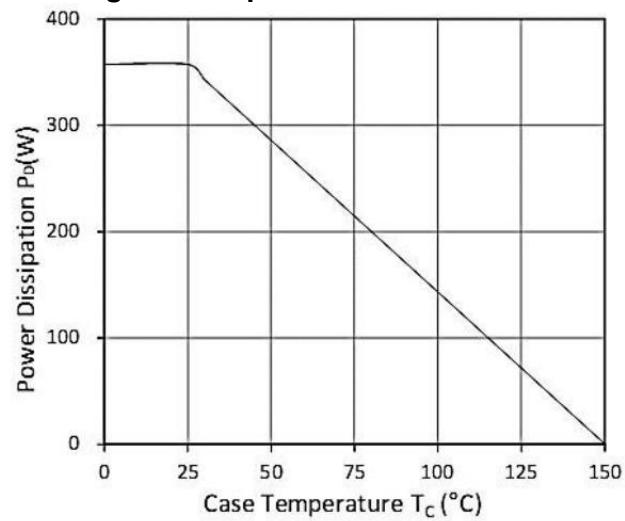
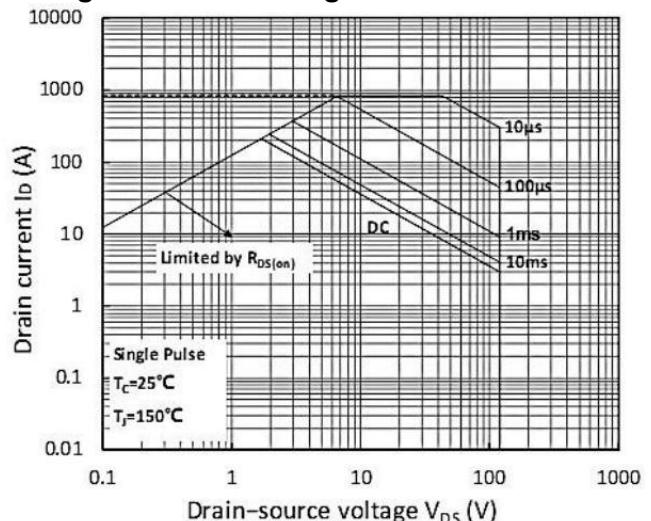
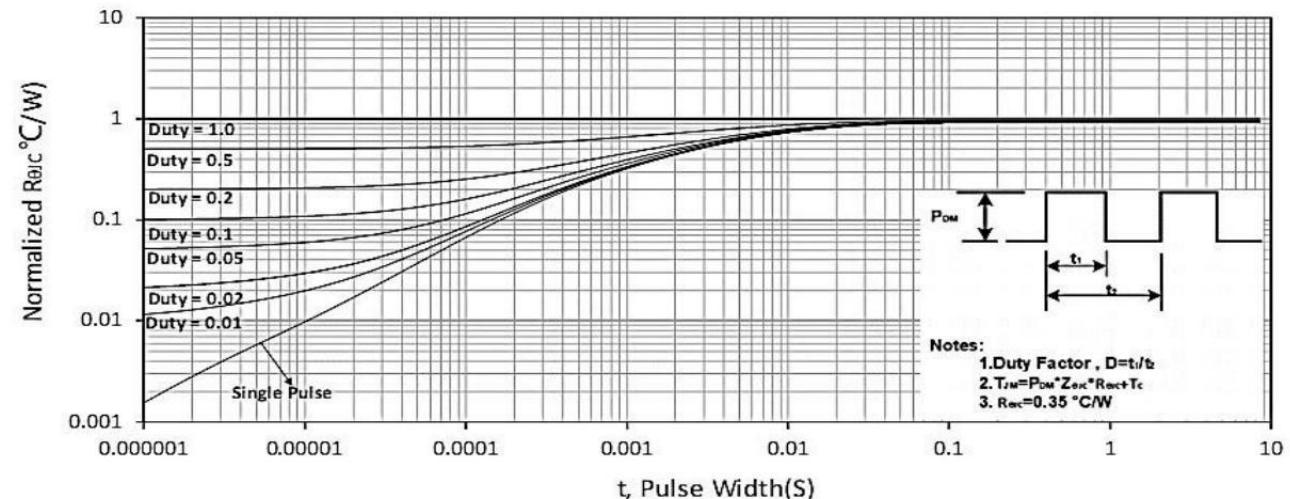
Electrical Characteristics ($T_c=25^\circ\text{C}$ unless otherwise noted)

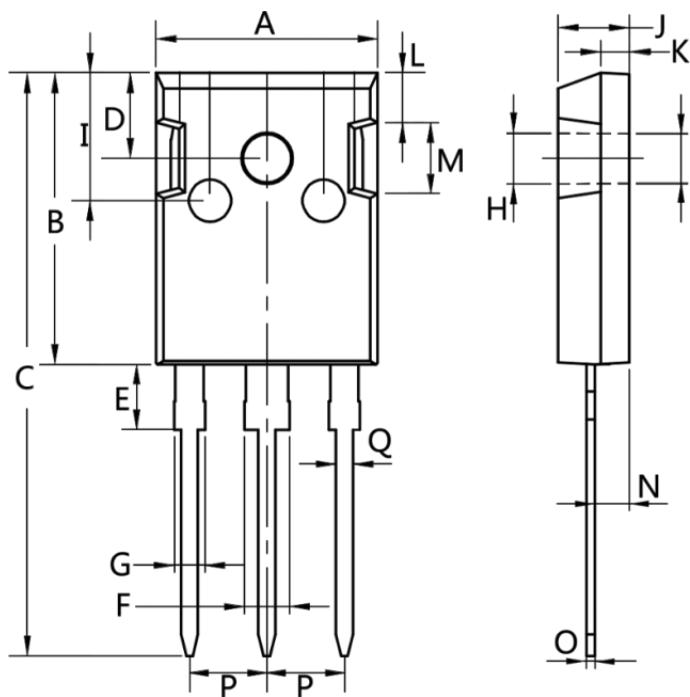
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V(BR)DSS	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}$, $I_D=250\mu\text{A}$	120	135	-	V
IGSS	Gate-body Leakage current	$V_{DS}=0\text{V}$, $V_{GS} = \pm 20\text{V}$	-	-	± 100	nA
IDSS	Zero Gate Voltage Drain Current $T_J=25^\circ\text{C}$	$V_{DS}=100\text{V}$, $V_{GS}=0\text{V}$	-	-	1	μA
IDSS	Zero Gate Voltage Drain Current $T_J=100^\circ\text{C}$		-	-	100	
VGS(th)	Gate-Threshold Voltage	$V_{DS}=V_{GS}$, $I_D=250\mu\text{A}$	2.0	3.0	4.0	V
RDS(on)	Drain-Source on-Resistance ⁴	$V_{GS}=10\text{V}$, $I_D=20\text{A}$	-	2.7	3.6	$\text{m}\Omega$
gfs	Forward Transconductance ⁴	$V_{DS}=10\text{V}$, $I_D=20\text{A}$	-	76	-	S
Ciss	Input Capacitance	$V_{DS}=60\text{V}$, $V_{GS}=0\text{V}$, $f=1\text{MHz}$	-	11500	-	pF
Coss	Output Capacitance		-	1600	-	
Crss	Reverse Transfer Capacitance		-	44	-	
R _g	Gate Resistance	$f=1\text{MHz}$	-	2.3	-	Ω
Q _g	Total Gate Charge	$V_{GS}=10\text{V}$, $V_{DS}=60\text{V}$, $I_D=20\text{A}$	-	168	-	nC
Q _{gs}	Gate-Source Charge		-	42	-	
Q _{gd}	Gate-Drain Charge		-	40	-	
td(on)	Turn-on Delay Time	$V_{GS}=10\text{V}$, $V_{DD}=60\text{V}$, $R_G=3\Omega$, $I_D=20\text{A}$	-	31.5	-	ns
t _r	Rise Time		-	86	-	
td(off)	Turn-off Delay Time		-	90	-	
t _f	Fall Time		-	54	-	
trr	Body Diode Reverse Recovery Time	$I=20\text{A}$, $dI/dt=100\text{A}/\mu\text{s}$	-	88	-	ns
Q _{rr}	Body Diode Reverse Recovery Charge		-	220	-	nC
VSD	Diode Forward Voltage ⁴	$I_D = 20\text{A}$, $V_{GS}=0\text{V}$	-	-	1.2	V
IS	Continuous Source Current $T_c=25^\circ\text{C}$		-	-	240	A

Notes:

- 1、The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2、The data tested by pulsed , pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
- 3、The EAS data shows Max. rating . The test condition is $V_{DD}=50\text{V}$, $V_{GS}=10\text{V}$, $L=0.5\text{mH}$, $I_{AS}=51\text{A}$
- 4、The power dissipation is limited by 150°C junction temperature
- 5、The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation.

Typical Characteristics**Figure 1. Output Characteristics****Figure 2. Transfer Characteristics****Figure 3. Forward Characteristics of Reverse****Figure 4. RDS(ON) vs. VGS****Figure 5. RDS(ON) vs. ID****Figure 6. Normalized RDS(on) vs. Temperature**

Typical Characteristics**Figure 7. Capacitance Characteristics****Figure 8. Gate Charge Characteristics****Figure 9. Power Dissipation****Figure10. Safe Operating Area****Figure 11. Normalized Maximum Transient Thermal Impedance**

Package Mechanical Data-TO-247-3L

Dim.	Min.	Max.
A	15.0	16.0
B	20.0	21.0
C	41.0	42.0
D	5.0	6.0
E	4.0	5.0
F	2.5	3.5
G	1.75	2.5
H	3.0	3.5
I	8.0	10.0
J	4.9	5.1
K	1.9	2.1
L	3.5	4.0
M	4.75	5.25
N	2.0	3.0
O	0.55	0.75
P	5.44 (BSC)	
Q	1.2	1.3

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
TAPING	TO-247-3L		330